

# Photodiode 100 mm<sup>2</sup> with Integrated Thin Film Filter



#### **FEATURES**

- 100 mm<sup>2</sup> Square Active Area
- Responsivity @ 13.5 nm 0.09 A/W
- Detection Range 12 nm to 18 nm
- Shipped with Protective Cover

## **Electro-Optical Characteristics at 25°C**

Parameters	Test Conditions	Min	Тур	Max	Units
Active Area	10 mm x 10 mm		100		mm <sup>2</sup>
Responsivity	(see graph on next page)	0.08	0.09	0.1	A/W
Dark Current	V <sub>R</sub> = 15 V		8	25	nA
Reverse Breakdown Voltage, V <sub>R</sub>	1 <sub>R</sub> = 1 μA	25			Volts
Capacitance, C	V <sub>R</sub> = 0 V	0.8	1	1.2	nF
Capacitance, C	V <sub>R</sub> = 12 V	220	260	350	pF
Response Time, tr	RL = $50 \Omega$ , $V_R = 12 V$		30		nsec

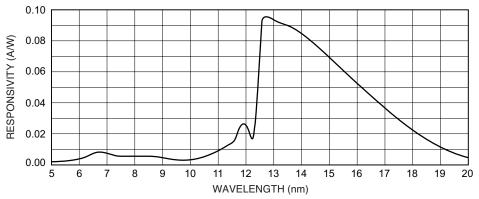
## **Thermal Parameters**

Storage and Operating Temperature Range	Units		
Ambient	–10° to 40°C		
Nitrogen or Vacuum	–20 to 80°C		
Lead Soldering Temperature*	260°C		

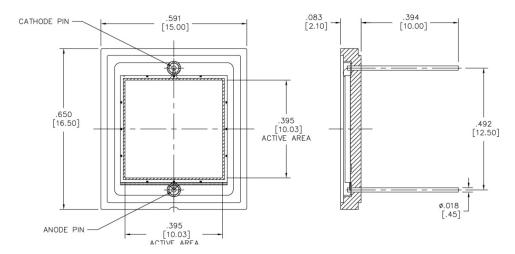
<sup>\*0.080&</sup>quot; from case for 10 seconds.

Revision December 17, 2022 Page 1 of 2

#### Typical Responsivity at 25°C



#### **Package Information**



Dimensions are in inch [metric] units.

Specifications are subject to change without prior notice.

Revision December 17, 2022